## NSN 5961-01-084-2583

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-084-2583 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205ad **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 3.00 amperes off-state current, peak **Power Rating Per Characteristic:** 6.25 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surface option gold **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/547 government specification Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

Demilitarization: